
	<h2 style="color: red;">HGTP7N60A4D</h2>
	<p>Hersteller-Teilenummer: HGTP7N60A4D</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: IGBT 600V 34A 125W TO220AB</p> <p>Datenblätter: 1.HGTP7N60A4D.pdf 2.HGTP7N60A4D.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 8030 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	HGTP7N60A4D
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	IGBT 600V 34A 125W TO220AB
Kategorie	Diskrete Halbleiterprodukte > Transistoren-IGBTs-
Teilstatus	8030 pcs Stock
detaillierte Beschreibung	IGBT 600V 34A 125W Through Hole TO-220AB
Serie	-
Eingabetyp	Standard
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Leistung - max	125W
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Rückwärts-Erholzeit (Trr)	34ns
Strom - Kollektor (Ic) (max)	34A
Spannung - Kollektor-Emitter-Durchbruch (max)	600V
IGBT-Typ	-
VCE (on) (Max) @ Vge, Ic	2.7V @ 15V, 7A
Strom - Collector Pulsed (Icm)	56A
Schaltenergie	55µJ (on), 60µJ (off)
Gate-Ladung	37nC
Td (ein / aus) bei 25 ° C	11ns/100ns
Testbedingung	390V, 7A, 25 Ohm, 15V
Verpackung	Tube
Basisteilenummer	HGTP7N60
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	HGTP7N60A4D_NL

HGTP7N60A4D ist neu im Original, Suche HGTP7N60A4D Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie HGTP7N60A4D AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage HGTP7N60A4D: Info@Y-IC.com

Sie können auch interessiert sein:

 HGTP7N60A4 G7N60A4 FSC HGTP7N60A4 G7N60A4 FSC	 HGTP7N60A4 Fairchild/ON Semiconductor IGBT 600V 34A 125W TO220AB	 HGTP7N60B3 FSC HGTP7N60B3 FSC	 HGTP7N60A4 AMI Semiconductor / ON Semiconductor IGBT 600V 34A 125W TO220AB
 HGTP7N60B Original HGTP7N60B Original	 HGTP7N60A4D Fairchild/ON Semiconductor IGBT 600V 34A 125W TO220AB	 HGTP7N60B3D AMI Semiconductor / ON Semiconductor IGBT 600V 14A 60W TO220AB	 HGTP7N60C3 HARRIS HGTP7N60C3 HARRIS

heiße Teile

Mehr

⚙ HGTP10N120BN	➔ HGTP10N40C1	➔ HGTP10N40E1D	D HGTP10N40F1D	➔ HGTP10N50C1
⚡ HGTP11N120CN	⚙ HGTP11N120CND	D HGTP12N60A4	➔ HGTP12N60A4	➔ HGTP12N60A4D
⚙ HGTP12N60A4D	⚡ HGTP12N60B3	⚙ HGTP12N60B3D	➔ HGTP12N60C3	➔ HGTP12N60C3
D HGTP14N36G3VL	⚙ HGTP14N40F3VL	⚡ HGTP14N41G3	⚙ HGTP15N120C3	➔ HGTP15N40C1
➔ HGTP15N50E1	➔ HGTP1N120BND	⚙ HGTP1N120CND	⚡ HGTP20N35G3VL	➔ HGTP20N36G3VL
➔ HGTP20N60A4	➔ HGTP20N60A4	D HGTP20N60B3	⚙ HGTP20N60B3D	⚡ HGTP20N60C3
⚙ HGTP20N60C3D	D HGTP2N120BN	➔ HGTP2N120BND	➔ HGTP2N120CN	➔ HGTP2N120CN
⚡ HGTP2N120CND	⚙ HGTP3N60A4	➔ HGTP3N60A4	➔ HGTP5N120BND	➔ HGTP5N120BND
⚙ HGTP7N60A4	⚡ HGTP7N60A4	⚙ HGTP7N60A4D	D HGTP7N60B3	➔ HGTP7N60B3D
➔ HGTP7N60B3D	⚙ HGTP7N60C3	⚡ HGTP7N60C3D	⚙ HGTP7N60C3D	➔ HGTP7NA60A4D

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited

